

Session 20 Frequency Response of Transistor Amplifiers: Exercises

Electronic Components and Circuits
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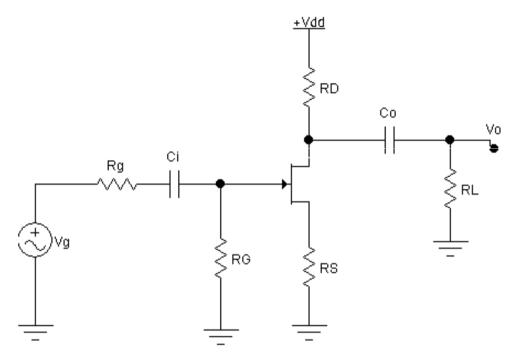
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Frequency response analysis of transistor amplifiers

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- Numerical resolution of an example, including the obtaining of the midband gain, the high cut-off frequency and the low cut-off frequency.
- Use of the former example to illustrate the methodology to obtain the bode plot.

Proposed Exercise



+Vdd = 15 V

$$R_S = 560\Omega$$

$$R_D = 5.6 \text{ K}\Omega$$

 $R_L = 10 \text{ K}\Omega$

$$C_i = 10 \mu F$$

 $C_0 = 10 \mu F$

$$R_G = 1 M\Omega$$

 $R_a = 50 \Omega$

$$R_g = 50 \Omega$$

Transistor:

$$I_{DSS}$$
= 10 mA $V_P = -2 V$

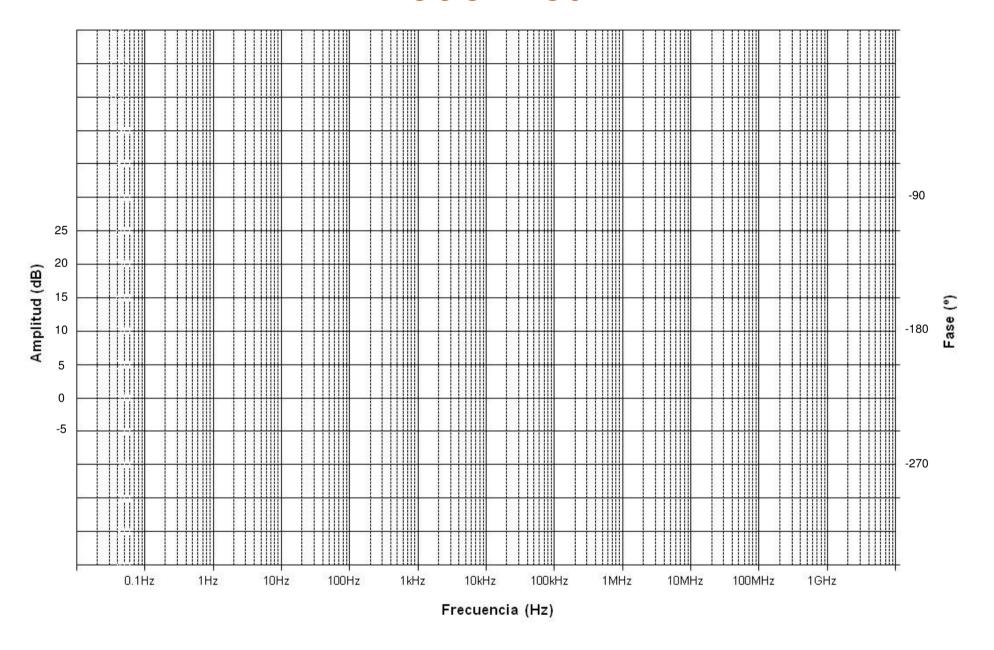
$$C_{gd}$$
=0.36 pF
 C_{gs} =1 pF

$$I_{D} = I_{DSS} \cdot (1 - V_{GS}/V_{P})^{2}$$

Proposed Exercise

- 1. Determination of the dc operating point of the BJT and the small-signal model parameters
- 2. Determination of the midband gain.
- 3. Determination of the high cut-off frequency using the open-circuit time constants method
- 4. Determination of the low cut-off frequency using the short-circuit time constants method
- 5. Drawing of the Bode Plot.

Bode Plot



Bode Plot

